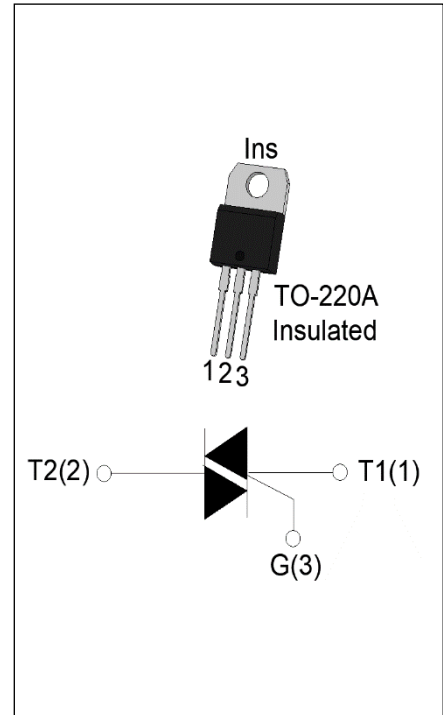


**JST24A-800B 25A TRIAC**

Rev.A.1.1

**DESCRIPTION:**

The JST24A-800B triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. By using an internal ceramic pad, JST24A-800B provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.


**MAIN FEATURES**

| Symbol                | Value       | Unit |
|-----------------------|-------------|------|
| $I_{T(RMS)}$          | 25          | A    |
| $V_{DRM}/V_{RRM}$     | 800         | V    |
| $I_{GT\ I/II/III/IV}$ | 50/50/50/70 | mA   |

**ABSOLUTE MAXIMUM RATINGS**

| Parameter                                                                                                         |        | Symbol              | Value   | Unit             |
|-------------------------------------------------------------------------------------------------------------------|--------|---------------------|---------|------------------|
| Storage junction temperature range                                                                                |        | T <sub>stg</sub>    | -40-150 | ℃                |
| Operating junction temperature range                                                                              |        | T <sub>j</sub>      | -40-125 | ℃                |
| Repetitive peak off-state voltage (T <sub>j</sub> =25℃)                                                           |        | V <sub>DRM</sub>    | 800     | V                |
| Repetitive peak reverse voltage (T <sub>j</sub> =25℃)                                                             |        | V <sub>RRM</sub>    | 800     | V                |
| RMS on-state current (T <sub>c</sub> ≤79℃)                                                                        |        | I <sub>T(RMS)</sub> | 25      | A                |
| Non repetitive surge peak on-state current<br>(full cycle , t <sub>p</sub> =20ms , T <sub>j</sub> =25℃)           |        | I <sub>TSM</sub>    | 250     | A                |
| Non repetitive surge peak on-state current<br>(full cycle , t <sub>p</sub> =16.6ms , T <sub>j</sub> =25℃)         |        |                     | 275     |                  |
| I <sup>2</sup> t value for fusing (t <sub>p</sub> =10ms , T <sub>j</sub> =25℃)                                    |        | I <sup>2</sup> t    | 340     | A <sup>2</sup> s |
| Critical rate of rise of on-state current<br>(I <sub>G</sub> =2×I <sub>GT</sub> , f=100Hz , T <sub>j</sub> =125℃) | I - II | di/dt               | 100     | A/μs             |
|                                                                                                                   | III-IV |                     | 50      |                  |
| Peak gate current (t <sub>p</sub> =20μs , T <sub>j</sub> =125℃)                                                   |        | I <sub>GM</sub>     | 4       | A                |
| Average gate power dissipation (T <sub>j</sub> =125℃)                                                             |        | P <sub>G(AV)</sub>  | 0.5     | W                |
| Peak gate power                                                                                                   |        | P <sub>GM</sub>     | 10      | W                |

|                                                                                      |          |   |    |
|--------------------------------------------------------------------------------------|----------|---|----|
| Peak pulse voltage<br>( $T_j=25^{\circ}\text{C}$ ; non-repetitive, off-state; FIG.7) | $V_{pp}$ | 2 | kV |
|--------------------------------------------------------------------------------------|----------|---|----|

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^{\circ}\text{C}$  unless otherwise specified)

| Symbol      | Test Condition                                                                     | Quadrant     | Value |      | Unit             |
|-------------|------------------------------------------------------------------------------------|--------------|-------|------|------------------|
| $I_{GT}$    | $V_D=12\text{V}$ $R_L=33\Omega$                                                    | I - II - III | MAX.  | 50   | mA               |
|             |                                                                                    | IV           |       | 70   |                  |
| $V_{GT}$    |                                                                                    | ALL          | MAX.  | 1    | V                |
| $V_{GD}$    | $V_D=V_{DRM}$ $T_j=125^{\circ}\text{C}$<br>$R_L=3.3\text{k}\Omega$                 | ALL          | MIN.  | 0.2  | V                |
| $I_L$       | $I_G=1.2I_{GT}$                                                                    | I - III - IV | MAX.  | 80   | mA               |
|             |                                                                                    | II           |       | 120  |                  |
| $I_H$       | $I_T=500\text{mA}$                                                                 |              | MAX.  | 80   | mA               |
| $dV/dt$     | $V_D=540\text{V}$ Gate Open $T_j=125^{\circ}\text{C}$                              |              | MIN.  | 1000 | V/ $\mu\text{s}$ |
| $(dV/dt)_c$ | $(dI/dt)_c=13.3\text{A/ms}$ , $T_j=125^{\circ}\text{C}$                            |              | MIN.  | 12   | V/ $\mu\text{s}$ |
| $t_{on}$    | $I_G=80\text{mA}$ $I_A=400\text{mA}$ $I_R=40\text{mA}$<br>$T_j=25^{\circ}\text{C}$ |              | TYP.  | 3    | $\mu\text{s}$    |
| $t_{off}$   |                                                                                    |              |       | 50   |                  |

**STATIC CHARACTERISTICS**

| Symbol    | Parameter                                |                           | Value(MAX.) | Unit             |
|-----------|------------------------------------------|---------------------------|-------------|------------------|
| $V_{TM}$  | $I_{TM}=35\text{A}$ $t_p=380\mu\text{s}$ | $T_j=25^{\circ}\text{C}$  | 1.5         | V                |
| $V_{TO}$  | Threshold voltage                        | $T_j=125^{\circ}\text{C}$ | 0.75        | V                |
| $R_D$     | Dynamic resistance                       | $T_j=125^{\circ}\text{C}$ | 18          | $\text{m}\Omega$ |
| $I_{DRM}$ | $V_D=V_{DRM}$ $V_R=V_{RRM}$              | $T_j=25^{\circ}\text{C}$  | 5           | $\mu\text{A}$    |
| $I_{RRM}$ |                                          | $T_j=125^{\circ}\text{C}$ | 2           | mA               |

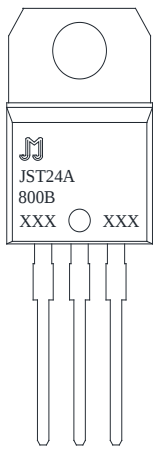
**THERMAL RESISTANCES**

| Symbol        | Parameter                | Value | Unit                 |
|---------------|--------------------------|-------|----------------------|
| $R_{th(j-c)}$ | junction to case (AC)    | 1.3   | $^{\circ}\text{C/W}$ |
| $R_{th(j-a)}$ | junction to ambient (AC) | 60    | $^{\circ}\text{C/W}$ |

ORDERING INFORMATION

|                                   |        |                  |                  |                                 |                                             |
|-----------------------------------|--------|------------------|------------------|---------------------------------|---------------------------------------------|
| J                                 | ST     | 24               | A                | -800                            | B                                           |
| JieJie Microelectronics Co., Ltd. | Triacs | $I_{T(RMS)}:25A$ | $A:TO-220A(Ins)$ | $800:V_{DRM}/V_{RRM} \geq 800V$ | $B:I_{GT1-3} \leq 50mA \ I_{GT4} \leq 70mA$ |

MARKING

|                                                                                     |                                                                         |
|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------|
|  | <p>XXX XXX</p> <p>Year _____<br/>Month _____</p> <p>Production Code</p> |
|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------|

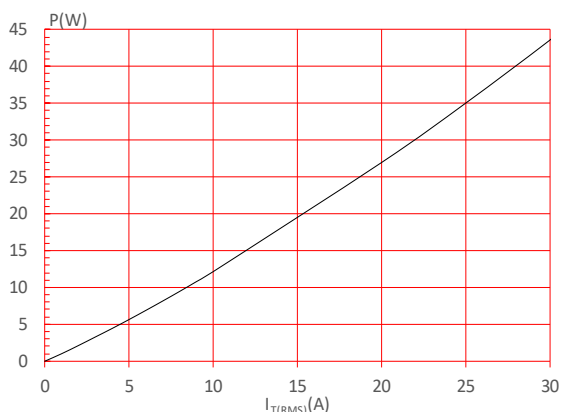
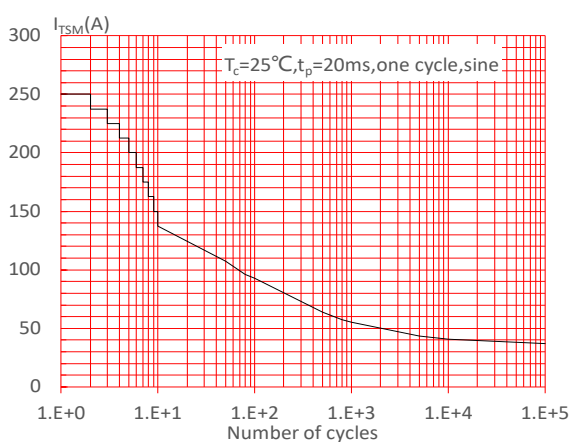
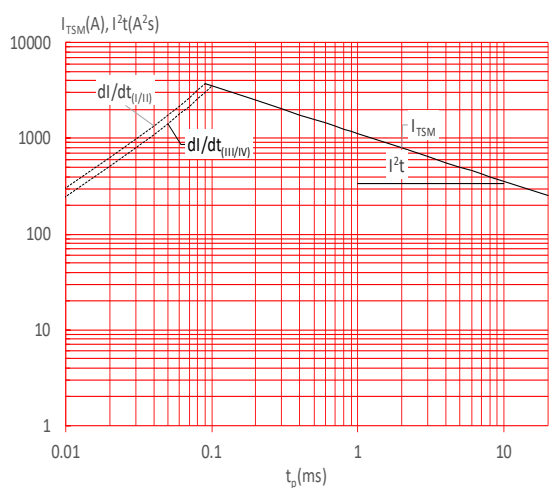
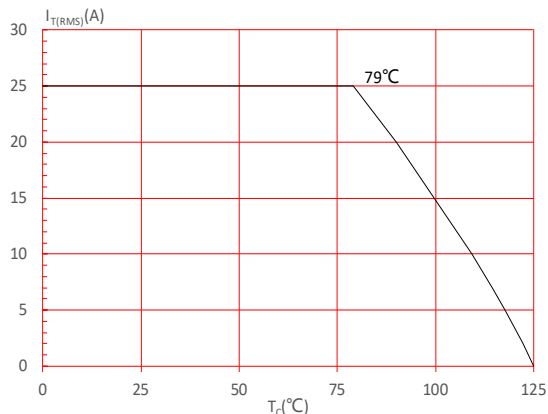
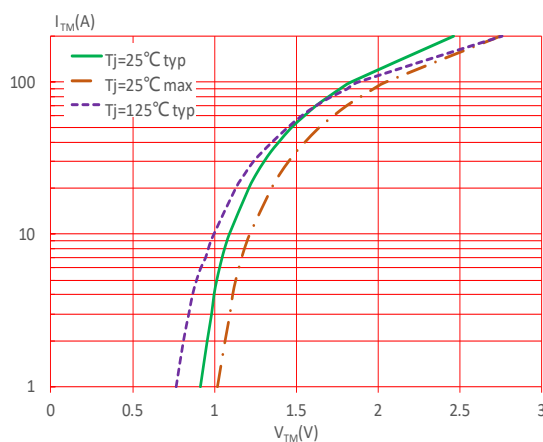
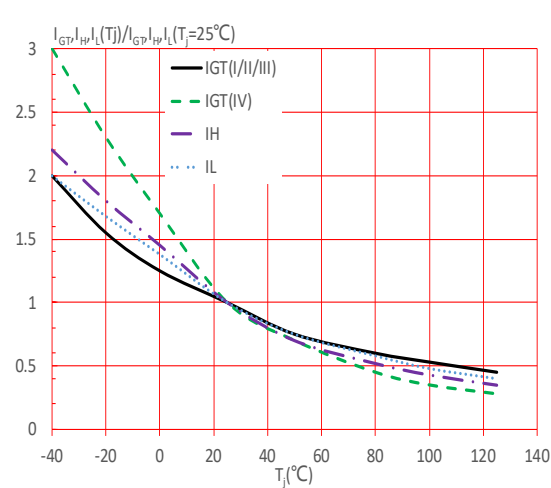
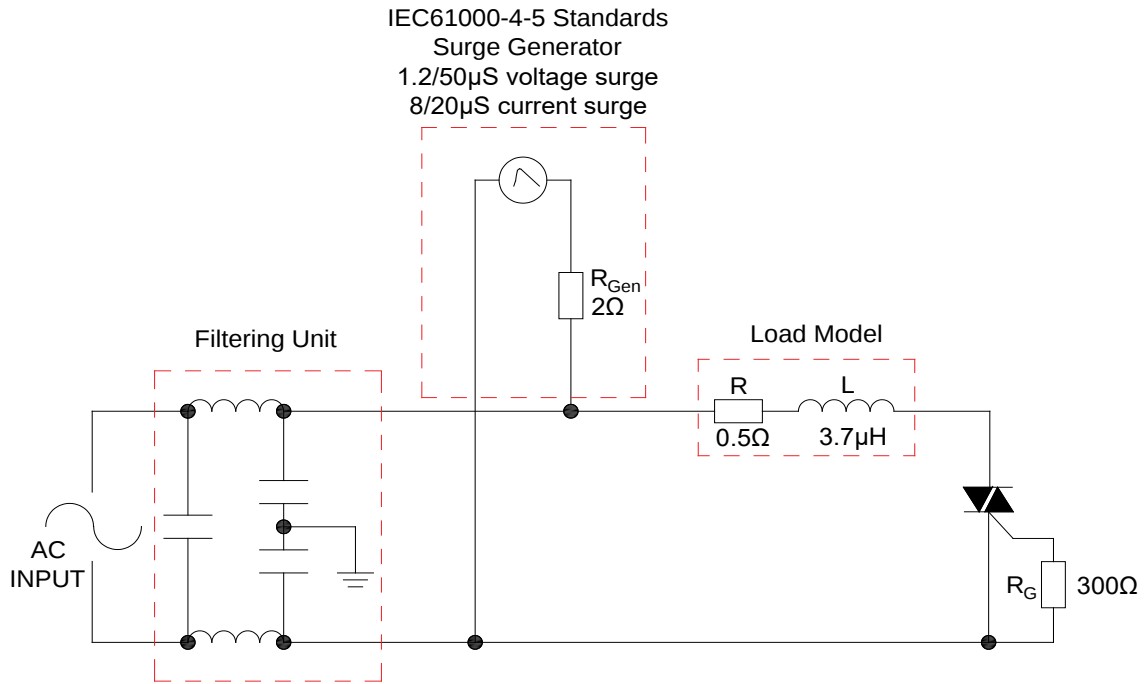
**FIG.1:** Maximum power dissipation versus RMS on-state current**FIG.3:** Surge peak on-state current versus number of cycles**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20ms$ , and corresponding value of  $I^2t$  (I - II:  $di/dt < 100A/\mu s$ ; III-IV:  $di/dt < 50A/\mu s$ )**FIG.2:** RMS on-state current versus case temperature**FIG.4:** On-state characteristics**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



## LEAD FORMING AND SOLDERING

Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics

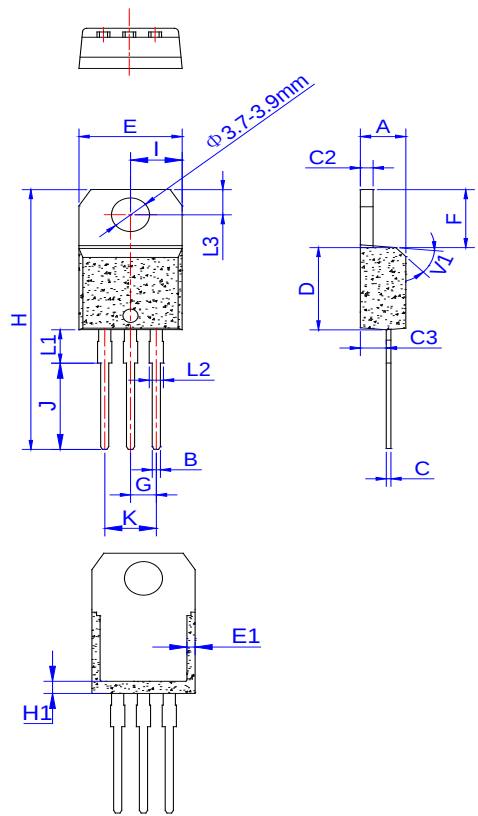
## ORDERING INFORMATION

| Order code  | Voltage<br>$V_{\text{DRM}}/V_{\text{RRM}}$ (V) | IGT(mA)      |    | Package      | Base qty.<br>(pcs) | Delivery mode |
|-------------|------------------------------------------------|--------------|----|--------------|--------------------|---------------|
|             |                                                | I - II - III | IV |              |                    |               |
| JST24A-800B | 800                                            | 50           | 70 | TO-220A(Ins) | 50                 | Tube          |

## Document Revision History

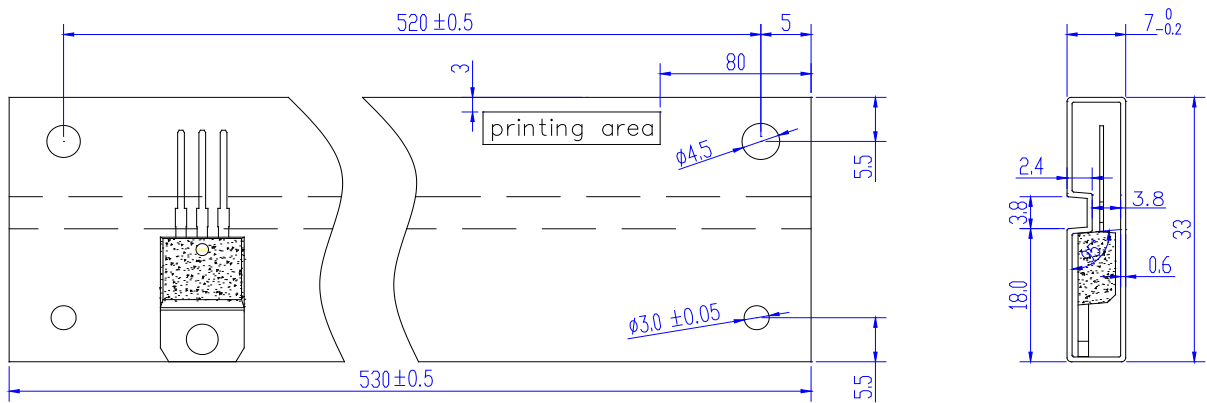
| Date         | Revision | Changes                        |
|--------------|----------|--------------------------------|
| Apr.14, 2023 | A.1.0    | Last updated                   |
| Oct.13, 2025 | A.1.1    | Revise PACKAGE MECHANICAL DATA |

PACKAGE MECHANICAL DATA



| Ref. | Dimensions  |      |       |        |      |       |
|------|-------------|------|-------|--------|------|-------|
|      | Millimeters |      |       | Inches |      |       |
|      | Min.        | Typ. | Max.  | Min.   | Typ. | Max.  |
| A    | 4.40        |      | 4.60  | 0.173  |      | 0.181 |
| B    | 0.61        |      | 0.88  | 0.024  |      | 0.035 |
| C    | 0.46        |      | 0.70  | 0.018  |      | 0.028 |
| C2   | 1.21        |      | 1.32  | 0.048  |      | 0.052 |
| C3   | 2.40        |      | 2.72  | 0.094  |      | 0.107 |
| D    | 8.60        |      | 9.70  | 0.339  |      | 0.382 |
| E    | 9.80        |      | 10.40 | 0.386  |      | 0.409 |
| E1   | 1.00        |      | 1.40  | 0.039  |      | 0.055 |
| F    | 6.25        |      | 6.85  | 0.246  |      | 0.270 |
| G    | 2.40        |      | 2.70  | 0.094  |      | 0.106 |
| H    | 28.00       |      | 29.80 | 1.102  |      | 1.173 |
| H1   | 1.80        |      | 2.20  | 0.071  |      | 0.087 |
| I    | 4.80        |      | 5.20  | 0.189  |      | 0.205 |
| J    | 9.55        |      | 9.95  | 0.376  |      | 0.392 |
| K    | 4.80        |      | 5.20  | 0.189  |      | 0.205 |
| L1   | 3.45        |      | 4.05  | 0.136  |      | 0.159 |
| L2   | 1.14        |      | 1.70  | 0.045  |      | 0.067 |
| L3   | 2.65        |      | 2.95  | 0.104  |      | 0.116 |
| V1   |             | 45°  |       |        | 45°  |       |

DELIVERY MODE



| PACKAGE | OUTLINE | TUBE (PCS) | INNER BOX (PCS) | PER CARTON |
|---------|---------|------------|-----------------|------------|
| TO-220A | TUBE    | 50         | 1,000           | 5,000      |

Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co., Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement.

Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information. This document supersedes and replaces all information previously supplied.



is a registered trademark of Jiangsu JieJie Microelectronics Co., Ltd.

Copyright © 2025 Jiangsu JieJie Microelectronics Co., Ltd. All rights reserved.